

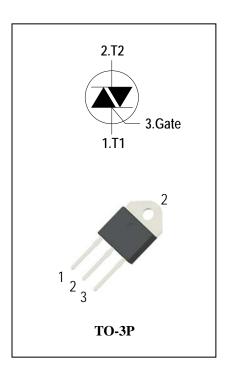
### 3 Quadrants High temperature Triacs

### **General Description**

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADS25CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance at given junction temperatures.

#### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 25 A)
- ♦ High Commutation dv/dt
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



### **Absolute Maximum Ratings**

Symbol	Items	Cond	Ratings	Unit	
$V_{DRM}$	Depotitive Deals Off State Voltage	T: - 25°C	ADS25CH60H	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS25CH80H	800	V
I <sub>T(RMS)</sub>	R.M.S On-State Current	T <sub>C</sub> = 105 °C	25	Α	
I <sub>TSM</sub>	Surge On-State Current	tp=20ms(50Hz)/tp=16.7	250/260	Α	
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		335	$A^2s$
-11/-14	Critical rate of rise of on-state F = 120 Hz Tj = 150°C			50	Δ /
dI/dt	current	$I_G = 2 \times I_{GT}$ , tr $\leq 100 \text{ ns}$	50	A/µs	
I <sub>GM</sub>	Peak Gate Current	tp = 20 μs Tj = 150°C	4	Α	
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
$P_GM$	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			10	W
T <sub>j</sub>	Operating Junction Temperature			- 40 ~ 150	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C





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### **ADS25CH60H/80H**

### **Electrical Characteristics**( Tj = 25°C unless otherwise specified )

Symbol	Items	Conditions		ADS25CH60H/80H			Unit	
					S	Blank	В	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 25°C		5		uA	
I <sub>RRM</sub>	Current		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 150°C	Max.	8.6		mA	
$V_{TM}$	Peak On-State Voltage		I <sub>TM</sub> = 35A, t <sub>p</sub> = 380 μs	Max.	1.5			V
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		V	
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	Max. 1.3			V		
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	10	35	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	20	50	75	mA
	Q1-Q3	Latabia a Commant	1 - 401	Max.	20	80	90	mA
ΙL	Q2	Latching Current	I <sub>G</sub> = 1.2 I <sub>GT</sub>		35	90	110	
dV/dt			$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	500	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		$V_D$ =400V Tj = 150°C (dl/dt)c=-12A/ms	Min.	1	15	20	V/µs
R <sub>th(j-c)</sub>	Junction to case (AC)			Max.	0.6			°C/W
$R_{th(j-a)}$	Junction to ambient			Max.	50			°C/W

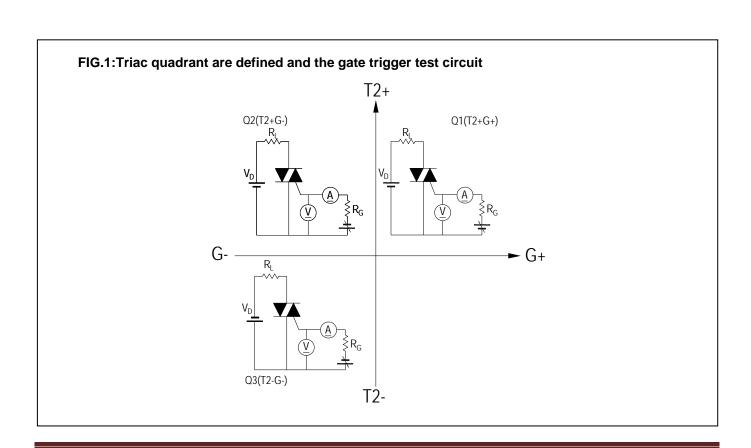


FIG.2: Maximum on-state power dissipation

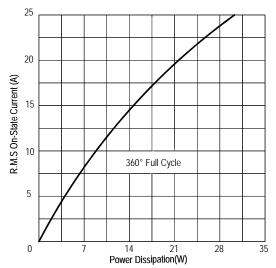


FIG.4: Maximum transient thermal impedance

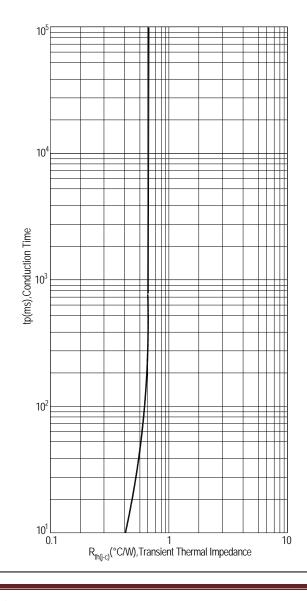


FIG.3: Typical RMS on-state current VS Allowable case Temperature

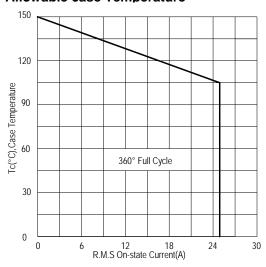


FIG.5: Rated surge on-state current (Non-Repetitive)

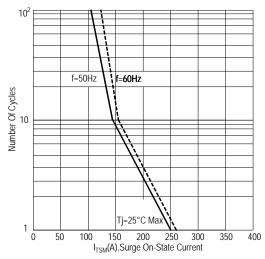
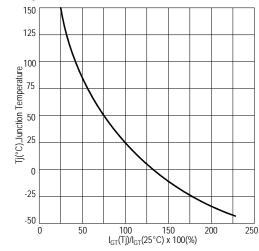


FIG.6: Gate trigger current VS Junction temperature





## **ADS25CH60H/80H**

FIG.7:Holding current and Latching current VS Junction temperature

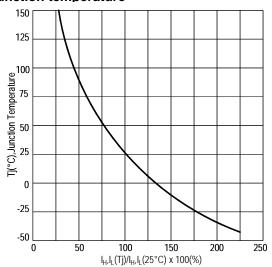


FIG.8: Gate trigger voltage VS Junction temperature

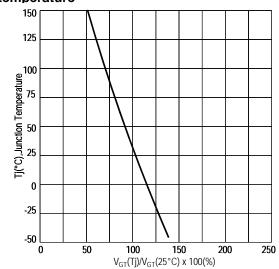
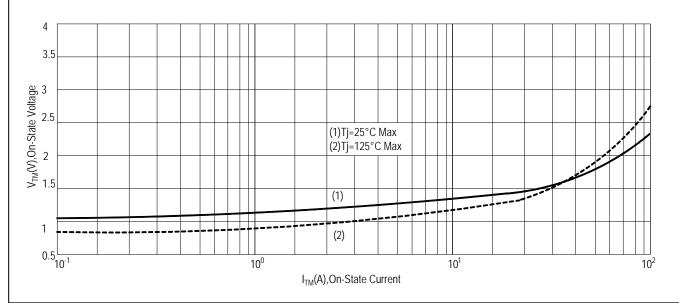


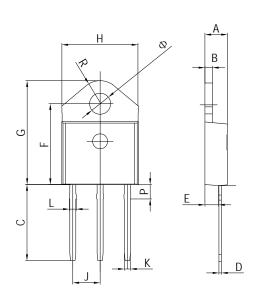
FIG.9: On-state characteristics(Max)



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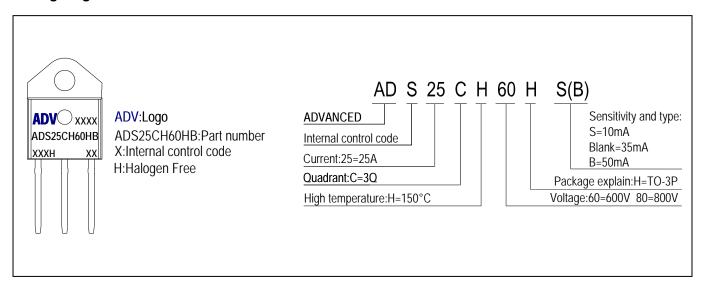


# PACKAGE MECHANICAL DATA TO-3P Package Dimension



	Dimensions In		Dimensions In		
Symbol	Millimeters		Inches		
	Min	Max	Min	Max	
Α	4.4	4.6	0.173	0.181	
В	1.45	1.55	0.057	0.061	
С	14.35	15.60	0.565	0.614	
D	0.5	0.7	0.020	0.028	
E	2.7	2.9	0.106	0.114	
F	15.8	16.5	0.622	0.650	
G	20.4	21.1	0.815	0.831	
Н	15.1	15.5	0.594	0.610	
J	5.4	5.65	0.213	0.222	
K	1.2	1.4	0.047	0.055	
Ø	4.08	4.20	0.161	0.165	
L	1.35	1.50	0.053	0.059	
Р	2.8	3.0	0.110	0.118	
R	4.60 typ.		0.181 typ.		

#### **Making Diagram**



### **Ordering information**

Part number	Package	Marking	Packing	Quantity			
ADS25CH60H#	TO-3P	ADS25CH60H#	Tube	30pcs			
ADS25CH80H#	TO-3P	ADS25CH80H#	Tube	30pcs			
Note:# = Gate Trigger Current Sensitivity and type							



### ADS25CH60H/80H

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